

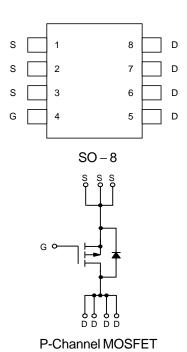
Features

- -30V/-5.3A, $R_{DS(ON)} = 60m\Omega(typ.)$ @ $V_{GS} = -10V$ $R_{DS(ON)} = 90m\Omega(typ.)$ @ $V_{GS} = -4.5V$
- Super High Density Cell Design
- Reliable and Rugged
- SO-8 Package

Applications

Power Management in Notebook Computer,
Portable Equipment and Battery Powered
Systems

Pin Description



Absolute Maximum Ratings $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter	Rating	Unit
V _{DSS}	Drain-Source Voltage	-30	V
V _{GSS}	Gate-Source Voltage	±20	V
I _D	Maximum Drain Current – Continuous T _A = 25°C	-4.6	۸
I _{DM}	Maximum Drain Current – Pulsed	-20	

TF reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.